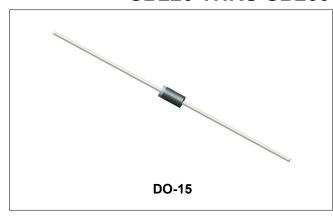






SB220 THRU SB260 SCHOTTKY RECTIFIER



Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Green Products in Compliance with the RoHS Directive
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: JEDEC DO-15 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
- · Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.014 ounce, 0.40 grams

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Characteristics	Symbol	SB220	SB230	SB240	SB250	SB260	Units
Maximum repetitive peak reverse voltage Maximum DC blocking voltage	V _{RRM} V _{DC}	20	30	40	50	60	V
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	V
Maximum average forward rectified current 0.375"(9.5mm) lead length at $T_L \! = \! 100 ^{\circ}\!$	I _(AV)			2.0			А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	50				А	
Maximum instantaneous forward voltage at 2.0A	V _F		0.5		0.7	70	V
Maximum DC reverse current T_A =25 $^{\circ}$ C at rated DC blocking voltage T_A =100 $^{\circ}$ C	I _R	5.0 10			mA		
Typical junction capacitance (Note 1)	CJ	170 140		0	pF		
Typical thermal resistance junction to lead	R _{0JL}	15			°C/W		
Typical thermal resistance junction to ambient(Note 2)	R _{θJA}	50.0			°C/W		
Operating junction and storage temperature range	T _J ,T _{STG}	-65 to +150				°C	

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

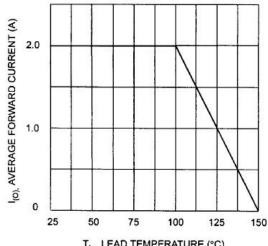
- 3. Thermal resistance from junction to ambient at 0.375"(9.5mm) lead length, P.C.B mounted.
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 sales@ smc-diodes.com



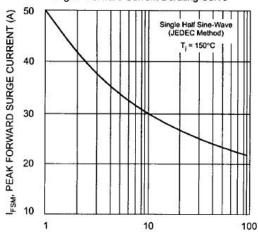




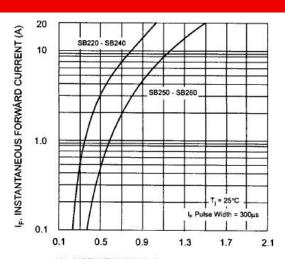
Ratings and Characteristics Curves



T_L, LEAD TEMPERATURE (°C) Fig. 1 Forward Current Derating Curve



NUMBER OF CYCLES AT 60 Hz Fig. 3 Max Non-Repetitive Peak Fwd Surge Current



V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics

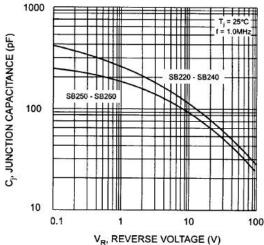
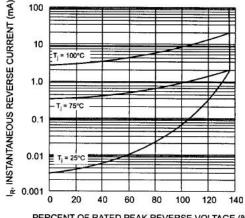


Fig. 4 Typical Junction Capacitance



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

Fig. 5 Typical Reverse Characteristics

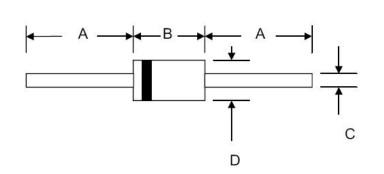
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Mechanical Dimensions DO-15



SYMBOL	Millin	neters	Inches		
O'IMBOL	Min.	Max.	Min.	Max.	
А	25.4	-	1.000	-	
В	5.5	7.62	0.217	0.300	
С	0.7	0.9	0.028	0.034	
D	2.6	3.6	0.104	0.140	

Ordering Information

Device	Package	Shipping
SB220	50.45(5).5	
THRU	DO-15(Pb-Free)	3000pcs / tape
SB260		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

Where XXXXX is YYWWL

 SB
 = Device Type

 2
 = Forward Current (2A)

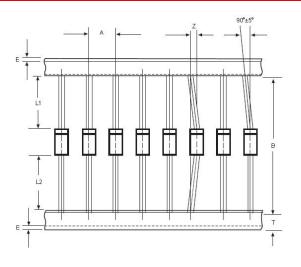
 40
 = Reverse Voltage (40V)

 SSG
 = SSG

YY = Year WW = Week L = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DO-15



SYMBOL	Millimeters			
	Min.	Max.		
А	4.50	5.50		
В	50.9	53.9		
Z	-	1.20		
Т	5.60	6.40		
Е	-	0.80		
IL1-L2I	-	1.0		

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